

DG2707

Vishay Siliconix

High Speed, Low Voltage, 3 Ω, Differential 4:1 CMOS Analog Multiplexer/Switch

DESCRIPTION

The DG2707 is a high speed, low voltage, 3 Ω , differential 4:1 multiplexer. It operates from a 1.65 V to 4.3 V single power supply. All channels guaranteed break before make switching. When powered with single 3.15 V supply, channel to channel ON Resistance matching is within 0.3 Ω .

All control logic input has 0.5 V to 1.65 V threshold. The EN pin enables cascading of the multiplexers. It features a 120 MHz - 3 dB bandwidth, - 90 dB crosstalk and - 70 dB off-isolation at 1 MHz.

The DG2707 comes in a small miniQFN-16 lead package (1.8 mm x 2.6 mm x 0.75 mm). As a committed partner to community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations and is 100 % RoHS complicant.

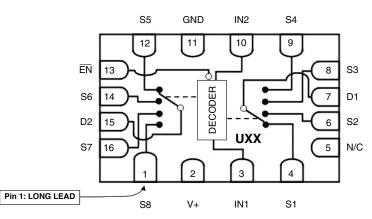
FEATURES

- Low voltage operation (1.65 V to 4.3 V)
- Low on-resistance R_{ON} : 2.8 Ω typ. at 3.15 V
- Low voltage logic threshold
- Low crosstalk: 70 dB
- High off-isolation: 90 dB
- Ultra small package: miniQFN16 of 1.8 mm x 2.6 mm

APPLICATIONS

- A/V and analog signal routing
- · Battery operated devices
- Data acquisition systems
- · Communications systems
- Medical and ATE equipments

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



miniQFN-16L

Top View

Device Marking: U<u>XX</u> Traceability Code: U is DG2707DN <u>XX</u> = Date/Lot

| ORDERING INFORMAT | ERING INFORMATION | | | |
|-------------------|-------------------|----------------|--|--|
| Temp. Range | Package | Part Number | | |
| - 40 °C to 85 °C | miniQFN-16 | DG2707DN-T1-E4 | | |





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| TRUTH TABLE DG2707 MULTIPLEXER, MINIQFN-16L | | | | | | | |
|---|--------------|-------------|----------------------|--------------|--|--|--|
| Enable Input | Select Input | | On Switches (Pin) | | | | |
| EN (Pin 13) IN2 (Pin 10) | | IN1 (Pin 3) | Description (Pin) | Common (Pin) | | | |
| 0 | 0 | 0 | S5 (Pin 12) | | | | |
| 0 | 0 | 1 | S6 (Pin 14) | DQ (Dim 15) | | | |
| 0 | 1 | 0 | S7 (Pin 16) | D2 (Pin 15) | | | |
| 0 | 1 | 1 | S8 (Pin 1) | | | | |
| 0 | 0 | 0 | S1 (Pin 4) | | | | |
| 0 | 0 | 1 | S2 (Pin 6) | D1 (Pin 7) | | | |
| 0 | 1 | 0 | D1 S3 (Pin 8) | | | | |
| 0 | 1 | 1 | S4 (Pin 9) | | | | |
| 1 | Х | Х | All Switches are off | | | | |
| | | | Pin 5 N/C | | | | |

| ABSOLUTE MAXIMUM RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted) | | | | | | |
|---|--|---------------------|------|--|--|--|
| Parameter | | Limit | Unit | | | |
| Reference to GND | V+ | - 0.3 to 5.0 | V | | | |
| | EN, IN, D _X , S _X ^a | - 0.3 to (V+ + 0.3) | V | | | |
| Current (Any terminal except S_X or D_X) | | 30 | | | | |
| Continuous Current (S _X or D _X) | | ± 300 | mA | | | |
| Peak Current (Pulsed at 1 ms, 10 % Duty | / Cycle) | ± 500 | | | | |
| Storage Temperature (D Suffix) | | - 65 to 150 | °C | | | |
| Thermal Resistance (Package) ^b | miniQFN-16 | 152 | °C/W | | | |
| Power Dissipation (Packages) ^b | miniQFN-16 ^{c, d} | 525 | mW | | | |

Notes:

a. Signals on S_X or D_X, or IN_X or EN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 6.6 mW/°C above 70 °C

d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.



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| SPECIFICATIONS (V | + = 3.15 V) | | | | | | | |
|--|--------------------------------------|---|--------------------|----------------------------|-------|-------------------|---|---|
| | | | | Limits - 40 °C to 85 °C | | | | |
| _ | | Test Conditions | _ h | | | | | |
| Parameter | Symbol | Otherwise Unless Specified | Temp. ^b | Min. ^u | Тур." | Max. ^u | Unit | |
| Analog Switch | | | | 1 | | 1 | | |
| Analog Signal Range ^e | V _{analog} | R _{DS(on)} | Full | 0 | | V+ | V | |
| On Resistance | R _{DS(on)} | V+ = 3.15 V, IS_X = 10 mA, VD_X = 1.0 V | Room Full | | 2.8 | 5.5 6 | | |
| R _{ON} Match | $\Delta R_{(on)}$ | V+ = 3.15 V, IS _X = 10 mA, VD _X = 1.0 V | Room | | 0.3 | | Ω | |
| R _{ON} Resistance Flatness | R _(on) Flatness | V+ = 3.15 V, IS_X = 10 mA, VD_X = 0.0 V, 1.0 V | Room | | 0.6 | | | |
| | I _{SX(off)} | | Room | - 5 | | 5 | | |
| Channel-Off Leakage Current | I _{DX(off)} | V+ = 3.6 V, VS _X = 0.5 V/3 V, VD _X = 3 V/0.5 V | Full | - 10 | | 10 | | |
| | | | Room | - 10 | | 10 | nA | |
| Channel-On Leakage Current | I _{DX(on)} | V + = 3.6 V, VS_X , VD_X = 3 V/0.5 V | Full | - 20 | | 20 | Unit V Ω nA V μA pF dB MHz % MHz % PF | 1 |
| Digital Control | | | | • | 1 | 1 | 1 | |
| Input High Voltage | V _{INH} | | | 1.65 | | | | |
| Input Low Voltage | V _{INL} | | Full | | | 0.4 | V | |
| Input Current | I _{INL} or I _{INH} | V _{IN} = 0 or V+ | | - 1 | | 1 | μA | |
| Input Capacitance | C _{IN} | V+ = 3.15, f = 1 MHz | | | 5.1 | | pF | |
| Dynamic Characteristics | | | • | | | • | | |
| Break-Before-Make Time | + | | Room | | 1 | | | |
| Dieak-Deiole-Wake Time | t _{BBM} | | Full | 5 | | | | |
| Enable Turn-On Time | + | | Room | | 20 | 45 | | |
| Enable Turn-On Time | t _{ON(EN)} | VS _x = 1.5 V, R ₁ = 50 Ω, C ₁ = 35 pF | Full | | | 55 | | |
| Enable Turn-Off Time | + | $VS_X = 1.5 V, R_L = 50 \Omega_2, C_L = 35 \text{ pr}$ | Room | | 15 | 35 | ns | |
| Enable Turn-Oli Time | t _{OFF(EN)} | | Full | | | 45 | | |
| Transition Time | + | | Room | | 35 | 55 | | |
| Iransmon Time | t _{trans} | | Full | | | 65 | | |
| Charge Injection ^d | Q _{INJ} | $C_L = 1 \text{ nF}, \text{ R}_{\text{GEN}} = 0 \Omega, \text{ VS}_X = 2 \text{ V}$ | Room | | - 14 | | рС | |
| Off-Isolation ^d | OIRR | | Deam | | - 70 | | | |
| Crosstalk ^{d, f} | X _{TALK} | V+ = 3.15 V, f = 1 MHz, R_L = 50 Ω, C_L = 5 pF | Room | | - 90 | | ав | |
| Bandwidth ^d | BW | V+ = 3.15 V, R_L = 50 Ω, C_L = 5 pF, - 3 dB | Room | | 120 | | MHz | |
| Total Harmonic Distortion ^d | THD | V + = 3.15 V, R_{load} = 600 Ω | Room | | 0.02 | | % | |
| | C _{S(off)} | | | | 16 | | | |
| S _X , D _X Off Capacitance ^d | CD _{X(off)} | V+ = 3.15 V, f = 1 MHz Ro | Room | | 42 | | pF | |
| Channel-On Capacitance ^d | CD _{X(on)} | | | | 49 | | | |
| Power Supply | | | | | | | | |
| Power Supply Range | V+ | | | 1.65 | | 4.3 | V | |
| Power Supply Current | l+ | V _{IN} = 0 V or V+ | Full | | | 1 | μA | |
| | | | | | | | | |

Notes:

a. Room = 25 $^{\circ}$ C, Full = as determined by the operating suffix.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

c. Typical values are for design aid only, not guaranteed nor subject to production testing.

d. Guarantee by design, not subjected to production test.

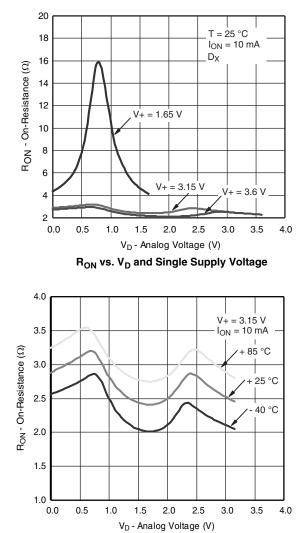
e. V_{IN} = input voltage to perform proper function.

f. Crosstalk measured between channels.

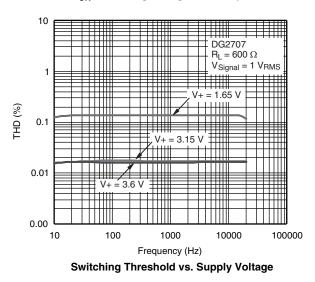
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

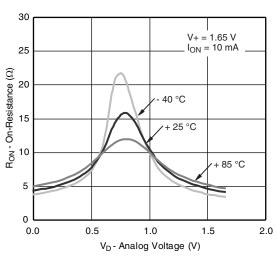


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

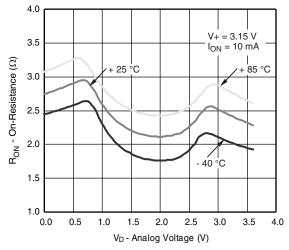




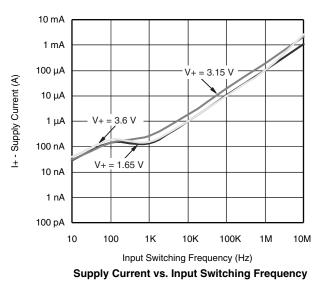




R_{ON} vs. Analog Voltage and Temperature



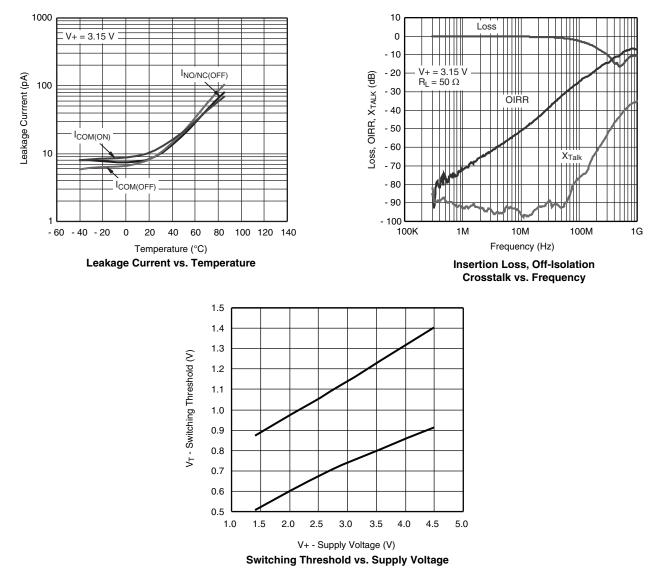
R_{ON} vs. Analog Voltage and Temperature





TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

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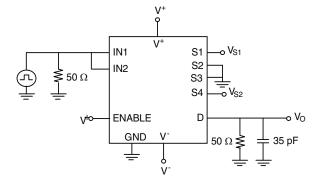


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TEST CIRCUITS



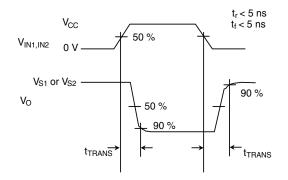
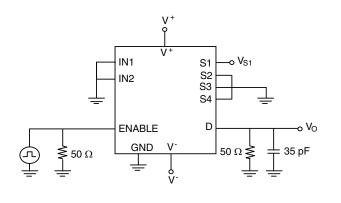
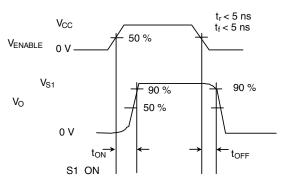
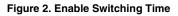


Figure 1. Transition Time







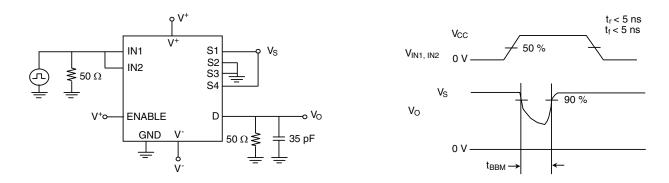
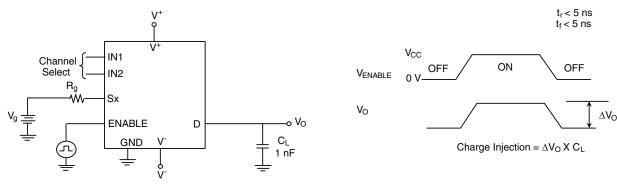


Figure 3. Break-Before Make

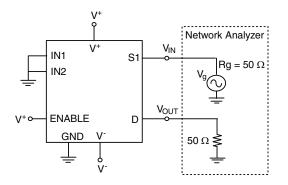


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TEST CIRCUITS

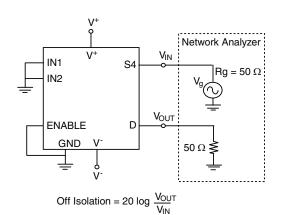


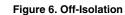




Insertion Loss = 20 log $\frac{V_{OUT}}{V_{IN}}$

Figure 5. Insertion Loss





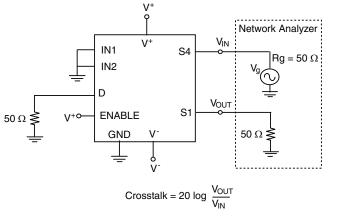


Figure 7. Crosstalk

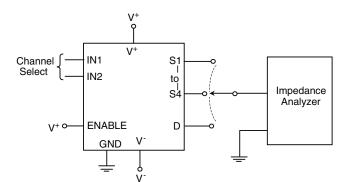


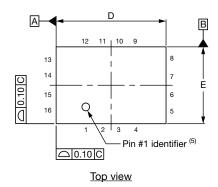
Figure 8. Source, Drain Capacitance

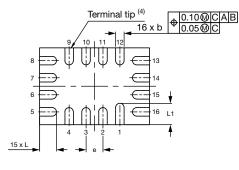
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg268397</u>.



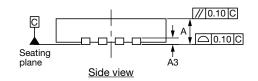
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Thin miniQFN16 Case Outline





Bottom view



| DIMENSIONS | MILLIMETERS ⁽¹⁾ | | | INCHES | | | |
|-------------------|----------------------------|------|------|------------|-------|-------|--|
| DIMENSIONS | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. | |
| A | 0.50 | 0.55 | 0.60 | 0.020 | 0.022 | 0.024 | |
| A1 | 0 | - | 0.05 | 0 | - | 0.002 | |
| A3 | 0.15 ref. | | | 0.006 ref. | | | |
| b | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 | |
| D | 2.50 | 2.60 | 2.70 | 0.098 | 0.102 | 0.106 | |
| е | 0.40 BSC | | | 0.016 BSC | | | |
| E | 1.70 | 1.80 | 1.90 | 0.067 | 0.071 | 0.075 | |
| L | 0.35 | 0.40 | 0.45 | 0.014 | 0.016 | 0.018 | |
| L1 | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 | |
| N ⁽³⁾ | 16 | | | 16 | | | |
| Nd ⁽³⁾ | 4 | | | 4 | | | |
| Ne ⁽³⁾ | | 4 | | | 4 | | |

Notes

⁽¹⁾ Use millimeters as the primary measurement.

- ⁽²⁾ Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- ⁽³⁾ N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.

 $^{(4)}$ Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.

⁽⁵⁾ The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.

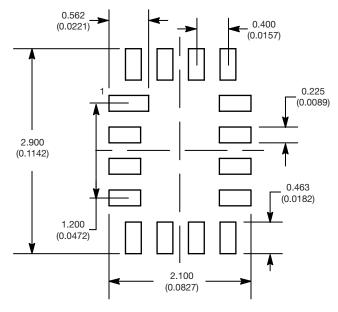
⁽⁶⁾ Package warpage max. 0.05 mm.

ECN: T16-0226-Rev. B, 09-May-16 DWG: 6023

1



RECOMMENDED MINIMUM PADS FOR MINI QFN 16L



Mounting Footprint Dimensions in mm (inch)



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